STUDY ON THE IRRADIA TION EFFECTS ON IRON NITRIDE BY HIGH ENERGY ELECTRONS AND IONS AT THE ATOMIC LEVEL

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The irradiation effects of high energy electrons and ions on the nitride in the compound layer of gas ion-nitrided pure iron, were studied by illuminating of 400KeV, 1MeV and 2MeV electrons and injecting of 100KV Xe ions in high voltage electron microscope (HVEM). The change of grain size, destruction of crystal lattices, formation of holes and bubbles, as well as the irradiation induced phase transformation, were investigated using transmission electron microscopy (TEM) and high resolution electron microscopy (HREM).

 γ -Fe₄N nitride was irradiated with 400KeV electrons with the dose rate of 6.8×10^{23} e/m²sec for 210 minutes. Extra spots appeared in the diffraction pattern and became sharp as shown in Fig1a to Fig.1c. The original HREM image after 7 minutes irradiation (Fig.1d) changed to a big configuration image after 118 minutes irradiation (Fig.1e). The extra spots in Fig.1c and the HREM image in Fig.1e were proved coming from Fe₃O₄ oxide, which was formed in Fe₄N nitride with the cubic-to-cubic orientation relationship. A new γ -Fe₄N nitride was also irradiated with 1MeV electrons with the dose rate of 1.8×10^{24} e/m²sec for 480 minutes. In spite of the formation of Fe₃O₄ oxide, the nanosized circular contrast presented in the original grain as shown in Fig.2, which indicates the destruction of irradiation on the crystal lattices.

2MeV electron irradiation was carried out on ε-Fe₂₋₃N nitride with the dose rate of 6.3×10^{24} e/m²sec for 35 minutes. With increasing the irradiation time, the specimen crystals had been heavily distorted with local bending, and the crystal lattice structures also changed locally. The original grains with the size of 400~600nm in the specimen, had changed to 3-10nm grains with distorted crystal lattices in the heavily damaged area. Some of the crystal lattices overlapped and also joined closely to each other. Moreover, the circular thin regions of 3-5nm in diameters were also produced. Some 2-3nm size areas showing complicated crystal structure images, had been analyzed with Fourier transformation and inverse FFT by selecting the known spots. The HREM image and the diffraction pattern before and after irradiation were shown in Fig.3a and Fig.3b, respectively. It is concluded that the Fe₃O₄ oxide transformed from ε-Fe₂₋₃N nitride with the orientation relationship of (110)ε//(2-20)Fe₃O₄ and [1-11]ε//[001]Fe₃O₄.

After 15 minutes irradiation of 100KV Xe ions with the dose rate of 1.27×10^{17} ions/m²sec for 15 minutes, γ -Fe₄N single crystal changed to small crystals in size of 1-5nm with various orientations within the range of 45 degree (see Fig.4). Compared with electron irradiation, the formation of Fe₃O₄ oxide was not observed under Xe ion irradiation, which seems to be due to the different irradiation effect between electrons and ions on the iron nitride specimen.

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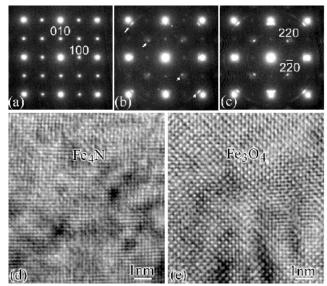


Fig.1 γ -Fe₄N irradiated by 400KeV electrons with (a) 0, (b) 64, (c) 123, (d) 7, and (e) 118minutes.

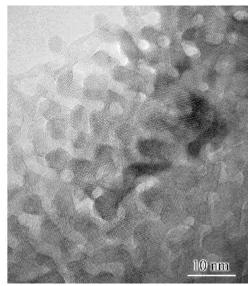


Fig.2 The image of γ -Fe₄N nitride irradiated by 1MeV electrons.

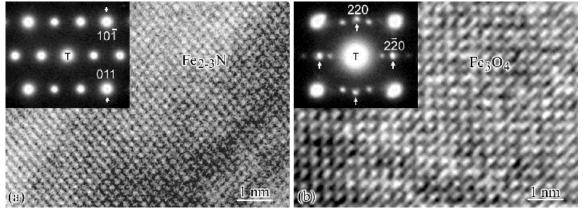


Fig.3 Initial HREM image and diffraction pattern of ε -Fe₂₋₃N nitride (a) and the formation of Fe₃O₄ oxide due to the 2MeV electron irradiation (b).

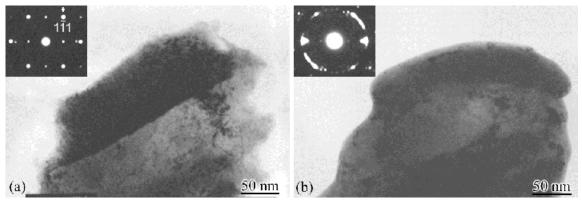


Fig.4 Bright field image and diffraction pattern of γ -Fe₄N nitride before (a) and after (b) 100KV Xe ion irradiation.